

As the below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name and that I believe I am an original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

## NON-VOLATILE SEMICONDUCTOR MEMORY STRUCTURE AND METHOD OF MANUFACTURE

<ul> <li>is attached hereto.</li> <li>was filed on</li> </ul>					
as Application Seri	al No	and was amended on		. <u></u> .	
pecification, including the I acknowledge the pplication in accordance I hereby claim fore pplication(s) for patent	he claims, as amended duty to disclose info e with Title 37, Code of ign priority benefits un or inventor's certificate inventor's certificate ha	and understand the content of by any amendment referred from attention which is material to a federal Regulations, § 1.0 der Title 35, Untied States (expensed below and have also aving a filing date before that	ed to above.  o the patent 56(a).  Code, § 119  identified bel	tability of too of any fore low any fore	
Number	Country	Date Filed(yyyy/mm/dd)	Yes	No	
90126141	Taiwan, R.O.C.	2001/10/23		X	
• • •	he Patent and Tradem (Reg. No. 43,33	6)			
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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patents issued thereon.

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